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## Temperature dependence of the capture cross section for the E3 defect in Ir/ZnO Schottky contacts

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### Abstract content <br> &nbsp; (Max 300 words)

We report on the temperature dependence of the capture cross-section observed in the E3 defect in Ir/ZnO Schottky contacts. Conventional DLTS measurements reveal an estimated activation enthalpy of 0.30eV. The peak height of the DLTS peaks show a significant dependence on the rate window used. From the temperature dependence of the capture cross-section, a capture barrier energy of 38meV has been calculated. The apparent capture cross-section for the E3 peak has been obtained as  $1.0 \times 10^{-14} \text{ cm}^2$  while the true capture cross-section has been calculated as  $7.3 \times 10^{-12} \text{ cm}^2$ . Saturation of the E3 defect is observed with a filling pulse of width 200ms. The variation of the peak height with rate window for the E3 peak is due to the temperature dependence of the capture cross-section.

### Apply to be<br> consider for a student <br> &nbsp; award (Yes / No)?

Yes

### Level for award<br>&nbsp;(Hons, MSc, <br> &nbsp; PhD)?

PhD

### Main supervisor (name and email)<br>and his / her institution

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### Would you like to <br> submit a short paper <br> for the Conference <br> Proceedings (Yes / No)?

No

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